



ZXTN5551FLQ

#### **160V NPN HIGH VOLTAGE TRANSISTOR IN SOT23**

#### Features

- BV<sub>CEO</sub> > 160V
- I<sub>C</sub> = 600mA High Collector Current
- Complementary PNP Type Available (ZXTP5401FLQ)
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The ZXTN5551FLQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

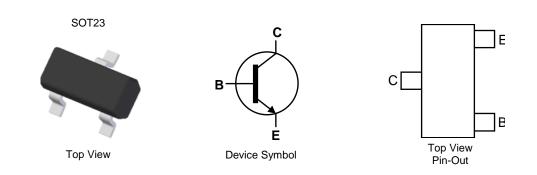
https://www.diodes.com/quality/product-definitions/

## **Mechanical Data**

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)

## Application

High voltage amplification



# Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN5551FLQTA	Automotive	N51	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



N51 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Key

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code		J	K	L	М	Ν	0	Р	R	S	Т	U
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



#### Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	180	V
Collector-Emitter Voltage	V <sub>CEO</sub>	160	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Continuous Collector Current (Note 5)	Ιc	600	mA

#### Thermal Characteristics (@ T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	PD	330	mW
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{ ext{ heta}JA}$	379	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

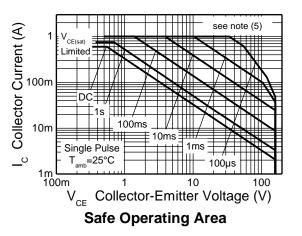
#### ESD Ratings (Note 6)

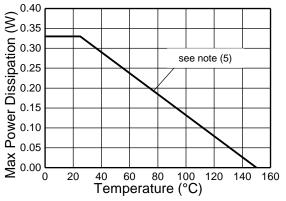
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Charged Device Model	ESD CDM	1000	V	C3

Notes:

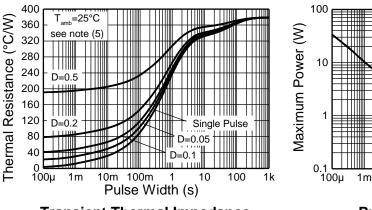
5. For a device mounted on 25mm x 25mm pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

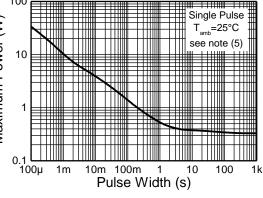




### **Derating Curve**



Transient Thermal Impedance



**Pulse Power Dissipation** 



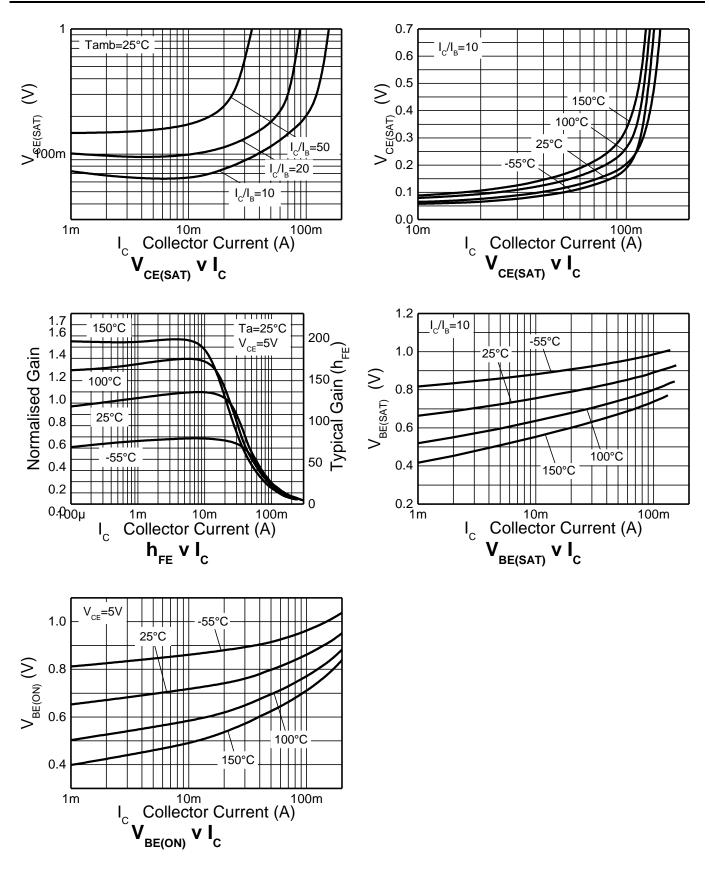
# Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	180	270	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	160	200	_	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	6	7	_	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>		<1 —	50 50	nA μA	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>A</sub> = 100°C
ON CHARACTERISTICS (Note 7)	·			•	•	•
DC Current Gain	h <sub>FE</sub>	80 80 30	135 145 65	 250 	_	$      I_{C} = 10 m A, V_{CE} = 5 V \\       I_{C} = 10 m A, V_{CE} = 5 V \\       I_{C} = 50 m A, V_{CE} = 5 V $
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	_	65 115	150 200	V	$I_{C} = 10$ mA, $I_{B} = 1$ mA $I_{C} = 50$ mA, $I_{B} = 5$ mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	—	760 840	1000 1200	mV	$I_{C} = 10$ mA, $I_{B} = 1$ mA $I_{C} = 50$ mA, $I_{B} = 5$ mA
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	Cobo			6	pF	$V_{CB} = 10V, f = 1.0MHz$
Small Signal Current Gain	h <sub>fe</sub>	50	_	260	_	$V_{CE} = 10V, I_C = 1mA,$ f = 1kHz
Transition Frequency	fT	_	130	_	MHz	$V_{CE} = 10V, I_C = 10mA,$ f = 1kHz
Delay time	t <sub>d</sub>		95		nS	
Rise Time	tr		64		nS	$V_{CC} = 10V, I_C = 10mA,$
Storage Time	ts		1256		nS	$I_{B1} = -I_{B2} = 1mA$
Fall Time	t <sub>f</sub>		140	_	nS	]

Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



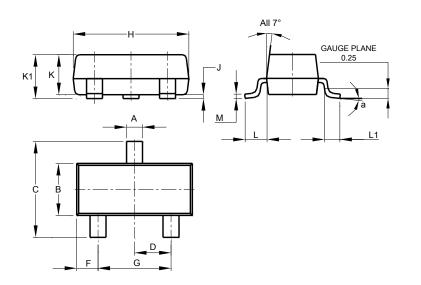
## Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)





# **Package Outline Dimensions**

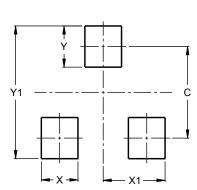
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23						
Dim	Min	Max	Тур			
A	0.37	0.51	0.40			
B	1.20	1.40	1.30			
_						
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
H	2.80	3.00	2.90			
J	0.013	0.10	0.05			
ĸ	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All	Dimens	ions in	mm			

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

ZXTN5551FLQ Document number: DS43755 Rev. 2 - 2



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